# Medium Power Transistor (32V, 2A) 2SD1766 / 2SD1758 / 2SD1862

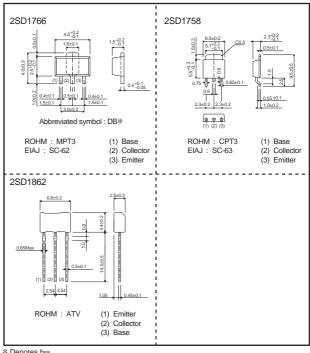
#### Features

- 1) Low VCE(sat). VCE(sat) = 0.5V(Typ.)(Ic/IB = 2A/0.2A)
- 2) Complements the 2SB1188 / 2SB1182 / 2SB1240.

#### Structure

Epitaxial planar type NPN silicon transistor

## ●External dimensions (Unit : mm)



\* Denotes hre

## ● Absolute maximum ratings (Ta=25°C)

	Parameter	Symbol	Limits	Unit	
Collector-base voltage		Vсво	40	V	
Collector-em	nitter voltage	Vceo	32	V	
Emitter-base voltage		V <sub>ЕВО</sub>	5	V	
Collector current		lc	2	A (DC)	
		Іср	2.5	A (Pulse) *1	
Collector power dissipation	2SD1766	Pc	0.5	W	
	2301700		2 *2		
	2SD1758		1	W	
			10	W (Tc=25°C)	
	2SD1862		1 *3	W	
Junction temperature		Tj	150	°C	
Storage temperature		Tstg	-55 to +150	°C	

<sup>\*1</sup> Single pulse, Pw=20ms

<sup>\*2</sup> When mounted on a 40×40×0.7 mm ceramic board.

<sup>\*3</sup> Printed circuit board: 1.7 mm thick, collector copper plating 1 cm² or lager.

#### ●Electrical characteristics (Ta=25°C)

Parameter		Symbol	Min.	Тур.	Max.	Unit	Conditions	
Collector-base breakdown voltage		ВУсво	40	_	_	V	Ic=50μA	
Collector-emitter breakdown voltage		BVceo	32	_	_	V	Ic=1mA	
Emitter-base breakdown voltage		ВУЕВО	5	_	_	V	Iε=50μA	
Collector cutoff current		Ісво	_	_	1	μΑ	Vcb=20V	
Emitter cutoff current		ІЕВО	_	_	1	μΑ	V <sub>EB</sub> =4V	
DC current transfer ratio	2SD1766,2SD1758,	hfe	82	_	390		Vc=3V. lc=0.5A	*
	2SD1862	1	120	_	390	_	_	VCE-0V, IC-0.0A
Collector-emitter saturation voltage		VCE(sat)	_	0.5	0.8	V	Ic/Iв=2A/0.2A	*
Transition frequency		f⊤	_	100	_	MHz	Vce=5V, Ie= -500mA, f=100MHz	*
Output capacitance		Cob	_	30	_	pF	Vcb=10V, Ie=0A, f=1MHz	

<sup>\*</sup> Measured using pulse current.

## ●Packaging specifications and hFE

		Package	Taping		
		Code	T100	TL	TV2
Туре	hre	Basic ordering unit (pieces)	1000	2500	2500
2SD1766	PQR		0	-	-
2SD1758	PQR			0	-
2SD1862	QR		_	-	0

#### hre values are classified as follows:

Item P		Q	R	
hfe	82 to 180	120 to 270	180 to 390	

#### •Electrical characteristic curves

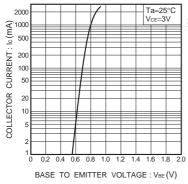


Fig.1 Grounded emitter propagation characteristics

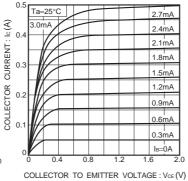


Fig.2 Grounded emitter output characteristics

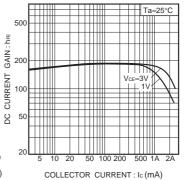


Fig.3 DC current gain vs. collector

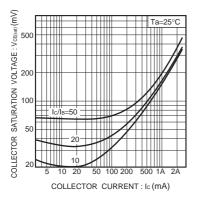


Fig.4 Collector-emitter saturation voltage vs. collector current

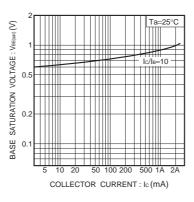


Fig.5 Collector-emitter saturation voltage vs. collector current

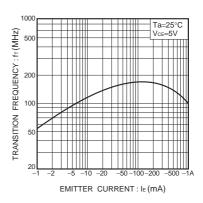


Fig.6 Transition frequency vs. emitter current

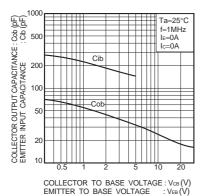


Fig.7 Collector output capacitance vs. collector-base voltage Emitter input capacitance vs. emitter-base voltage

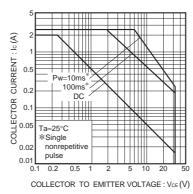


Fig.8 Safe operating area (2SD1766)

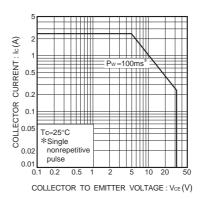


Fig.9 Safe operating area (2SD1758)

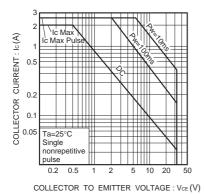


Fig.10 Safe operating area (2SD1862)

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